

Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.8)	V_{pp}	4.5	kV
--	----------	-----	----

ELECTRICAL CHARACTERISTICS (at $T_j=25$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12V$ $R_L=33$	- -	MAX.	50	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125$ $R_L=3.3k$	- -	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	-	MAX.	70	mA
				90	
I_H	$I_T=500mA$		MAX.	50	mA
dV/dt	$V_D=670V$ Gate Open $T_j=125$		MIN.	800	V/s
$(di/dt)_c$	G 9 G W F $T_j=125V$ 7		MIN.	20	A/ms
t_{on}	$I_G=80mA$ $I_A=400mA$ $I_R=40mA$ $T_j=25$		TYP.	5	s
t_{off}				50	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_{TM}=17A$ $t_p=380$ s	$T_j=25$	1.5	V
V_{TO}	Threshold voltage	$T_j=125$	0.77	V

ORDERING INFORMATION

J ST 12 E -1000 BW -/

JieJie Microelectronics Co., Ltd.

Triacs

BW: $I_{GT1-3} \leq 50\text{mA}$

1000: $V_{DRM} / V_{RRM} \geq 1000\text{V}$

FIG.1: Maximum power dissipation versus RMS on-state current

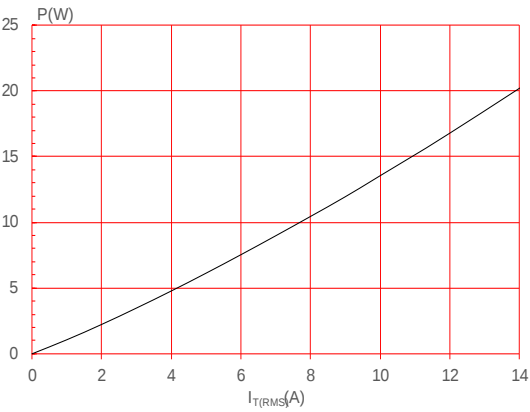


FIG.2: RMS on-state current versus case temperature

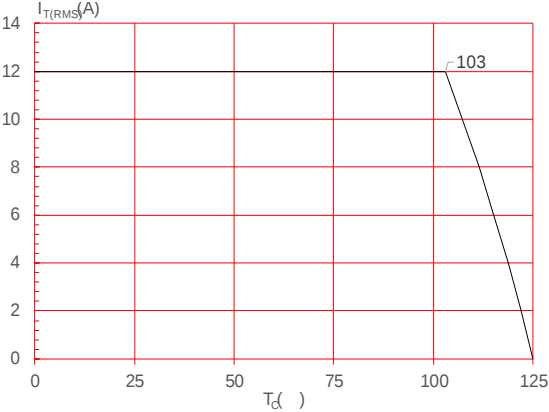


FIG.3: RMS on-state current versus ambient temperature (printed circuit board FR4,copper

W K L F N Q H V V P temperature range (M)-7.5 (4)-14.5 (on) TJ 0 Tc 0 Tw 3.602 (v)12.3 (er)4.5 (sf -15.8 (e

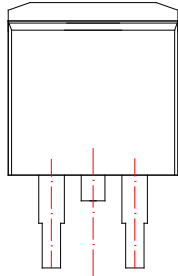
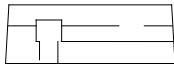
ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
JST12E-1000BW	1000	50	TO-263	50	Tube
JST12E-1000BW-TR				800	Tape & Reel

Document Revision History

Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated
Oct.20, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.370		0.378
D	2.40			0.094		
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033

DELIVERY MODE

